

## GAU, Faculty of Engineering

<b>Course Unit Title</b>	Digital Integrated Circuit Design	
<b>Course Unit Code</b>	EEN419	
<b>Type of Course Unit</b>	Technical Elective, Electrical and Electronics Engineering students	
<b>Level of Course Unit</b>	4th Year BSc	
<b>National Credits</b>	3	
<b>Number of ECTS Credits Allocated</b>	6 ECTS	
<b>Theoretical (hour/week)</b>	3	
<b>Practice (hour/week)</b>	-	
<b>Laboratory (hour/week)</b>	-	
<b>Year of Study</b>	4	
<b>Semester when the course unit is delivered</b>	7	
<b>Course Coordinator</b>	Prof. Dr. Ali Zeki	
<b>Name of Lecturer (s)</b>	Prof. Dr. Ali Zeki	
<b>Name of Assistant (s)</b>		
<b>Mode of Delivery</b>	Face to Face, E-learning activities	
<b>Language of Instruction</b>	English	
<b>Prerequisites and co-requisites</b>	EEN301 Electronic Circuits I	
<b>Recommended Optional Programme Components</b>	Basic background of Logic Circuit Design	
<b>Objectives of the Course:</b>		
<ul style="list-style-type: none"> <li>➤ Teaching transistor-level realization of basic MOS digital circuits</li> <li>➤ Teaching analysis of static behavior of basic MOS digital circuits</li> <li>➤ Teaching analysis of dynamic behavior of basic MOS digital circuits</li> </ul>		
<b>Learning Outcomes</b>		
When this course has been completed the student should be able to		Assessment
1	explain the need for and advantages of digital signals and circuits	1,2
2	plot the voltage transfer curve and extract the static parameters and noise margins of a given MOS inverter	1,2
3	build the transistor-level logic gate realizing a given Boolean function	1,2
4	calculate the propagation delays and rise/fall times of a given MOS inverter or gate	1,2
5	design transistor-level combinational and sequential digital circuits using classical (standard CMOS) as well as alternative approaches (transmission gates, dynamic logic)	1,2
6	determine the static and dynamic power consumption of a given MOS inverter or gate	1,2
7	analyze and design MOS memory cells (ROM, SRAM, DRAM)	1,2
Assessment Methods: 1. Written Exam, 2. Assignment, 3. Project/Report, 4. Presentation, 5 Lab. Work		
<b>Course's Contribution to Program</b>		CL
1	Ability to understand and apply knowledge of mathematics, science, and engineering	5
2	Ability to design and conduct experiments as well as to analyze and interpret data	3
3	Ability to work in multidisciplinary teams while exhibiting professional responsibility and ethical conduct	2
4	Ability to apply systems thinking in problem solving and system design	5
5	Knowledge of contemporary issues while continuing to engage in lifelong learning	4
6	Ability to use the techniques, skills and modern engineering tools necessary for engineering practice	3
7	Ability to express their ideas and findings, in written and oral form	3
8	Ability to design and integrate systems, components or processes to meet desired needs within realistic constraints	5
9	Ability to approach engineering problems and effects of their possible solutions within a well structured, ethically responsible and professional manner	4
11	Strong foundation on the fundamentals of Electrical and Electronics Engineering such as Circuit Theory, Signals, Systems, Control and Communications, which are necessary for successful practice in the field	4
12	Awareness on the contemporary requirements, methods and applications of the Electrical and Electronics Engineering	5
CL: Contribution Level (1: Very Low, 2: Low, 3: Moderate, 4: High, 5:Very High)		

Course Contents			
Week	Theory	Application	Exams
1	Why Digital Circuits? Why Integrated Circuits? Physical and Electrical Properties of the MOS Transistor		
2	Ideal inverter, practical inverter and characteristics, resistive-load inverter		
3	Various types of NMOS inverters, CMOS inverter		
4	Static analysis and design of CMOS inverter		pop quiz #1
5	Dynamic analysis and design of CMOS inverter		
6	NAND, NOR gates, complex gates		
7	Static analysis and design of CMOS complex gates		pop quiz #2
8			Midterm
9	Dynamic analysis and design of CMOS complex gates		
10	Transmission gates		
11	Various flip-flop circuits		
12	Dynamic logic		Quiz
13	Read-only memories (ROM)		
14	static and dynamic random-access memories (SRAM and DRAM)		pop quiz #3
15			Final

#### Recommended Sources

**Textbook:** R. Boylestad & L. Nashelsky, "Electronic Devices and Circuit Theory", 10th edition, Prentice Hall, 2008.

**Supplementary Material(s):** A. Sedra & K.C. Smith, "Microelectronic Circuits", 6th edition, Oxford University Press, 2010.

#### Assessment

Attendance	5%	
Assignments	10%	
Midterm Exam	20%	
Quiz	15%	
Pop quizzes	10%	
Final Exam	40%	
Total	100%	

#### ECTS Allocated Based on the Student Workload

Activities	Number	Duration (hour)	Total Workload(hour)
Hours per week (Theoretical)	14	3	42
The preparation of the homeworks	5	8	40
Pop Quizzes	3	7	21
Quiz	1	16	16
Midterm Examination	1	22	22
Final Exam	1	27	27
Total Workload			168
ECTS Credit of the Course			6